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### Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Obsolete
Number of LABs/CLBs	1377
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	175
Number of Gates	10000
Voltage - Supply	4.5V ~ 5.5V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Package / Case	208-BFQFP Exposed Pad
Supplier Device Package	208-RQFP (28x28)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microsemi/a14100a-1rq208i">https://www.e-xfl.com/product-detail/microsemi/a14100a-1rq208i</a>

# 1 – ACT 3 Family Overview

## General Description

Microsemi's ACT 3 Accelerator Series of FPGAs offers the industry's fastest high-capacity programmable logic device. ACT 3 FPGAs offer a high performance, PCI compliant programmable solution capable of 186 MHz on-chip performance and 9.0 nanosecond clock-to-output (–1 speed grade), with capacities spanning from 1,500 to 10,000 gate array equivalent gates.

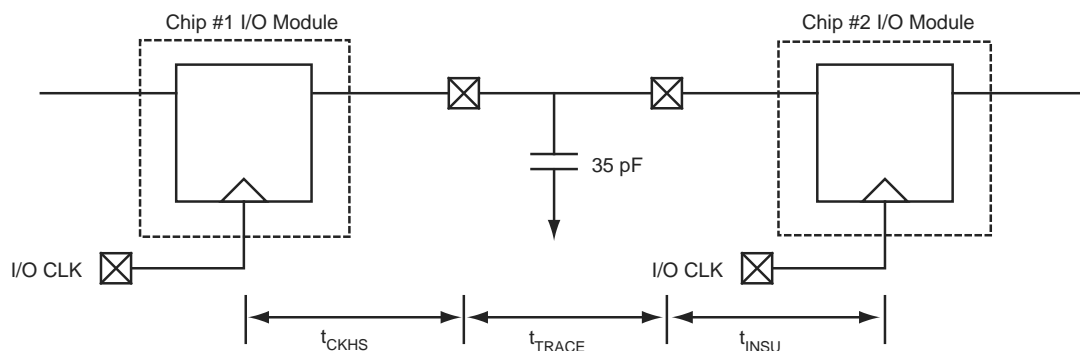
The ACT 3 family builds on the proven two-module architecture consisting of combinatorial and sequential logic modules used in Microsemi's 3200DX and 1200XL families. In addition, the ACT 3 I/O modules contain registers which deliver 9.0 nanosecond clock-to-out times (–1 speed grade). The devices contain four clock distribution networks, including dedicated array and I/O clocks, supporting very fast synchronous and asynchronous designs. In addition, routed clocks can be used to drive high fanout signals such as flip-flop resets and output.

The ACT 3 family is supported by Microsemi's Designer Series Development System which offers automatic placement and routing (with automatic or fixed pin assignments), static timing analysis, user programming, and debug and diagnostic probe capabilities.

Accumulators (16-Bit)	47 MHz
Loadable Counters (16-Bit)	82 MHz
Prescaled Loadable Counters (16-Bit)	186 MHz
Shift Registers	186 MHz

**Figure 1-1 • Predictable Performance (worst-case commercial, –1 speed grade)**

## System Performance Model



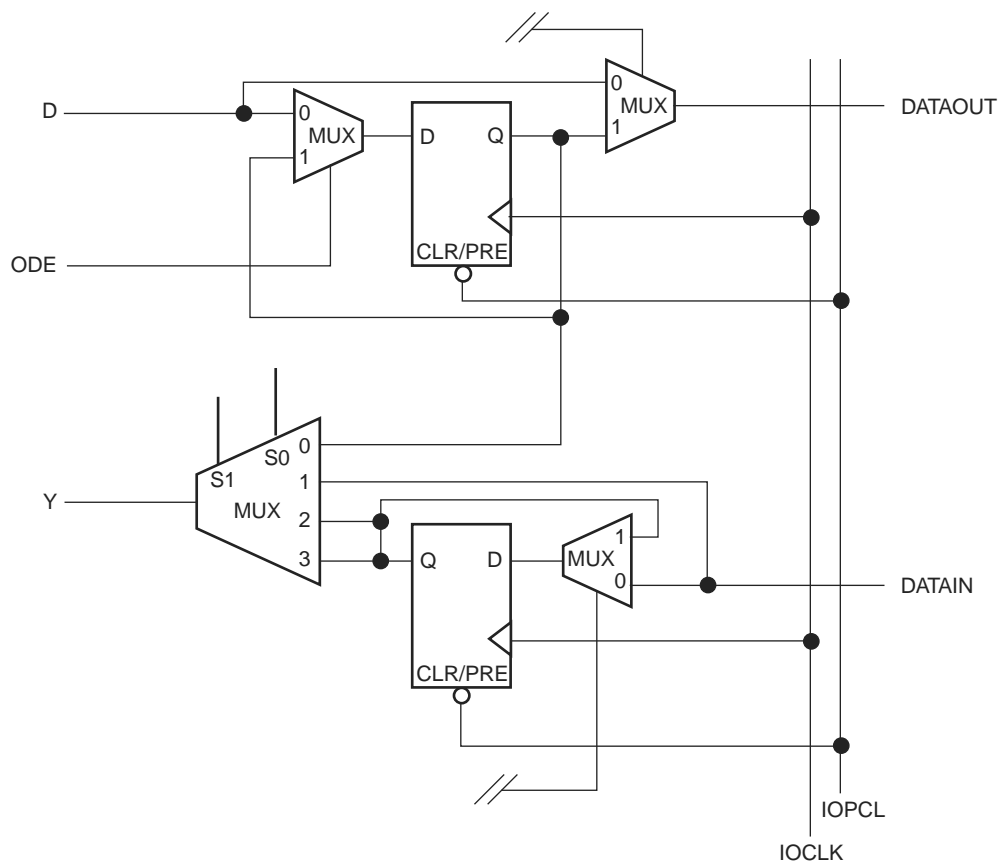
The S-module contains a full implementation of the C-module plus a clearable sequential element that can either implement a latch or flip-flop function. The S-module can therefore implement any function implemented by the C-module. This allows complex combinatorial-sequential functions to be implemented with no delay penalty. The Designer Series Development System will automatically combine any C-module macro driving an S-module macro into the S-module, thereby freeing up a logic module and eliminating a module delay.

The clear input CLR is accessible from the routing channel. In addition, the clock input may be connected to one of three clock networks: CLKA, CLKB, or HCLK. The C-module and S-module functional descriptions are shown in Figure 2-2 and Figure 2-3 on page 2-2. The clock selection is determined by a multiplexer select at the clock input to the S-module.

## I/Os

### I/O Modules

I/O modules provide an interface between the array and the I/O Pad Drivers. I/O modules are located in the array and access the routing channels in a similar fashion to logic modules. The I/O module schematic is shown in Figure 4. The signals DataIn and DataOut connect to the I/O pad driver.



**Figure 2-4 • Functional Diagram for I/O Module**

Each I/O module contains two D-type flip-flops. Each flip-flop is connected to the dedicated I/O clock (IOCLK). Each flip-flop can be bypassed by nonsequential I/Os. In addition, each flip-flop contains a data enable input that can be accessed from the routing channels (ODE and IDE). The asynchronous preset/clear input is driven by the dedicated preset/clear network (IOPCL). Either preset or clear can be selected individually on an I/O module by I/O module basis.

## 5 V Operating Conditions

**Table 2-2 • Absolute Maximum Ratings<sup>1</sup>, Free Air Temperature Range**

Symbol	Parameter	Limits	Units
VCC	DC supply voltage	–0.5 to +7.0	V
VI	Input voltage	–0.5 to VCC + 0.5	V
VO	Output voltage	–0.5 to VCC + 0.5	V
IIO	I/O source sink current <sup>2</sup>	±20	mA
T <sub>STG</sub>	Storage temperature	–65 to +150	°C

Notes:

- Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Device should not be operated outside the recommended operating conditions.
- Device inputs are normally high impedance and draw extremely low current. However, when input voltage is greater than VCC + 0.5 V for less than GND –0.5 V, the internal protection diodes will forward bias and can draw excessive current.

**Table 2-3 • Recommended Operating Conditions**

Parameter	Commercial	Industrial	Military	Units
Temperature range*	0 to +70	–40 to +85	–55 to +125	°C
5 V power supply tolerance	±5	±10	±10	%VCC

Note: \*Ambient temperature (T<sub>A</sub>) is used for commercial and industrial; case temperature (T<sub>C</sub>) is used for military.

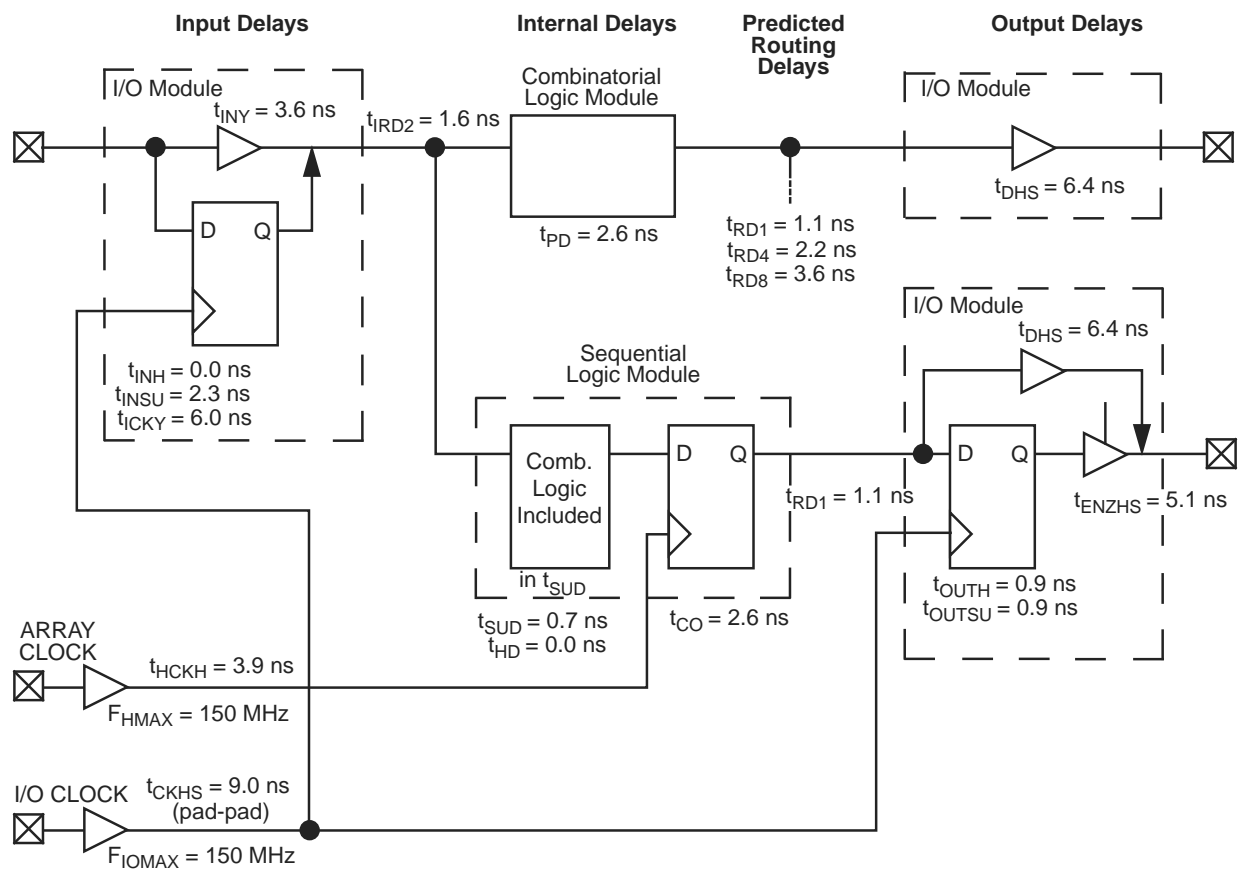
**Table 2-4 • Electrical Specifications**

Symbol	Parameter	Test Condition	Commercial		Industrial		Military		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
VOH <sup>1,2</sup>	High level output	IOH = –4 mA (CMOS)	–	–	3.7	–	3.7	–	V
		IOH = –6 mA (CMOS)	3.84						V
		IOH = –10 mA (TTL) <sup>3</sup>	2.40						V
VOL <sup>1,2</sup>	Low level output	IOL = +6 mA (CMOS)		0.33		0.4		0.4	V
		IOL = +12 mA (TTL) <sup>3</sup>		0.50					
VIH	High level input	TTL inputs	2.0	VCC + 0.3	2.0	VCC + 0.3	2.0	VCC + 0.3	V
VIL	Low level input	TTL inputs	–0.3	0.8	–0.3	0.8	–0.3	0.8	V
IIN	Input leakage	VI = VCC or GND	–10	+10	–10	+10	–10	+10	μA
IOZ	3-state output leakage	VO = VCC or GND	–10	+10	–10	+10	–10	+10	μA
C <sub>IO</sub>	I/O capacitance <sup>3,4</sup>			10		10		10	pF
ICC(S)	Standby VCC supply current (typical = 0.7 mA)			2		10		20	mA
ICC(D)	Dynamic VCC supply current. See the Power Dissipation section.								

Notes:

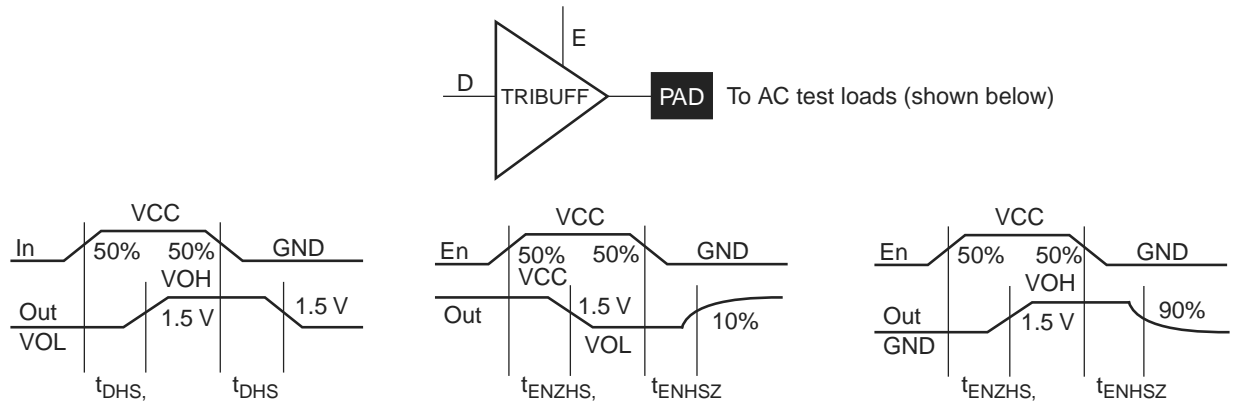
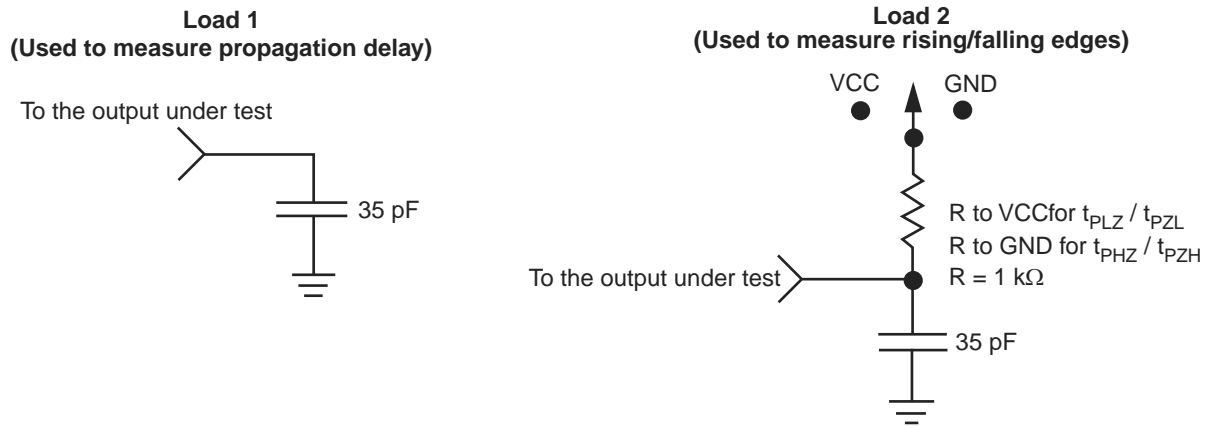
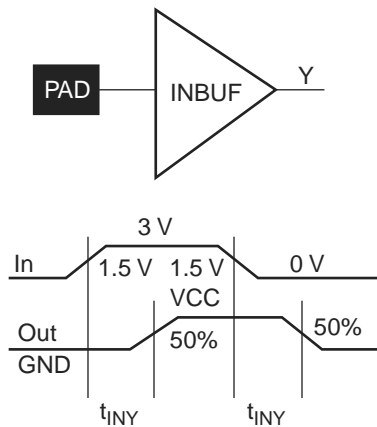
- Microsemi devices can drive and receive either CMOS or TTL signal levels. No assignment of I/Os as TTL or CMOS is required.
- Tested one output at a time, VCC = minimum.
- Not tested; for information only.
- V<sub>OUT</sub> = 0 V, f = 1 MHz
- Typical standby current = 0.7 mA. All outputs unloaded. All inputs = VCC or GND.

## ACT 3 Timing Model



Note: Values shown for A1425A -1 speed grade device.

**Figure 2-10 • Timing Model**


**Figure 2-11 • Output Buffers**

**Figure 2-12 • AC Test Loads**

**Figure 2-13 • Input Buffer Delays**

## Tightest Delay Distributions

Propagation delay between logic modules depends on the resistive and capacitive loading of the routing tracks, the interconnect elements, and the module inputs being driven. Propagation delay increases as the length of routing tracks, the number of interconnect elements, or the number of inputs increases.

From a design perspective, the propagation delay can be statistically correlated or modeled by the fanout (number of loads) driven by a module. Higher fanout usually requires some paths to have longer lengths of routing track. The ACT 3 family delivers the tightest fanout delay distribution of any FPGA. This tight distribution is achieved in two ways: by decreasing the delay of the interconnect elements and by decreasing the number of interconnect elements per path.

Microsemi's patented PLICE antifuse offers a very low resistive/capacitive interconnect. The ACT 3 family's antifuses, fabricated in 0.8 micron m lithography, offer nominal levels of 200Ω resistance and 6 femtofarad (fF) capacitance per antifuse. The ACT 3 fanout distribution is also tighter than alternative devices due to the low number of antifuses required per interconnect path. The ACT 3 family's proprietary architecture limits the number of antifuses per path to only four, with 90% of interconnects using only two antifuses.

The ACT 3 family's tight fanout delay distribution offers an FPGA design environment in which fanout can be traded for the increased performance of reduced logic level designs. This also simplifies performance estimates when designing with ACT 3 devices.

**Table 2-14 • Logic Module and Routing Delay by Fanout (ns); Worst-Case Commercial Conditions**

Speed Grade	FO = 1	FO = 2	FO = 3	FO = 4	FO = 8
ACT 3 –3	2.9	3.2	3.4	3.7	4.8
ACT 3 –2	3.3	3.7	3.9	4.2	5.5
ACT 3 –1	3.7	4.2	4.4	4.8	6.2
ACT 3 STD	4.3	4.8	5.1	5.5	7.2

Notes:

1. Obtained by added  $t_{RD(x=FO)}$  to  $t_{PD}$  from the Logic Module Timing Characteristics Tables found in this datasheet.
2. The –2 and –3 speed grades have been discontinued. Refer to PDN 0104, PDN 0203, PDN 0604, and PDN 1004 at <http://www.microsemi.com/soc/support/notifications/default.aspx#pdn>.

## Timing Characteristics

Timing characteristics for ACT 3 devices fall into three categories: family dependent, device dependent, and design dependent. The input and output buffer characteristics are common to all ACT 3 family members. Internal routing delays are device dependent. Design dependency means actual delays are not determined until after placement and routing of the user's design is complete. Delay values may then be determined by using the ALS Timer utility or performing simulation with post-layout delays.

### Critical Nets and Typical Nets

Propagation delays are expressed only for typical nets, which are used for initial design performance evaluation. Critical net delays can then be applied to the most time-critical paths. Critical nets are determined by net property assignment prior to placement and routing. Up to 6% of the nets in a design may be designated as critical, while 90% of the nets in a design are typical.

### Long Tracks

Some nets in the design use long tracks. Long tracks are special routing resources that span multiple rows, columns, or modules. Long tracks employ three and sometimes four antifuse connections. This increases capacitance and resistance, resulting in longer net delays for macros connected to long tracks. Typically up to 6% of nets in a fully utilized device require long tracks. Long tracks contribute approximately 4 ns to 14 ns delay. This additional delay is represented statistically in higher fanout (FO = 8) routing delays in the datasheet specifications section.

## A1440A, A14V40A Timing Characteristics (continued)

**Table 2-29 • A1440A, A14V40A Worst-Case Commercial Conditions, VCC = 4.75 V, T<sub>J</sub> = 70°C**

Dedicated (hardwired) I/O Clock Network		–3 Speed <sup>1</sup>		–2 Speed <sup>1</sup>		–1 Speed		Std. Speed		3.3 V Speed <sup>1</sup>		Units
Parameter/Description		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t <sub>ILOCKH</sub>	Input Low to High (pad to I/O module input)		2.0		2.3		2.6		3.0		3.5	ns
t <sub>IOPWH</sub>	Minimum Pulse Width High	1.9		2.4		3.3		3.8		4.8		ns
t <sub>IPOWL</sub>	Minimum Pulse Width Low	1.9		2.4		3.3		3.8		4.8		ns
t <sub>IOSAPW</sub>	Minimum Asynchronous Pulse Width	1.9		2.4		3.3		3.8		4.8		ns
t <sub>ILOCKSW</sub>	Maximum Skew		0.4		0.4		0.4		0.4		0.4	ns
t <sub>IOP</sub>	Minimum Period	4.0		5.0		6.8		8.0		10.0		ns
f <sub>IOMAX</sub>	Maximum Frequency		250		200		150		125		100	MHz
<b>Dedicated (hardwired) Array Clock</b>												
t <sub>HCKH</sub>	Input Low to High (pad to S-module input)		3.0		3.4		3.9		4.5		5.5	ns
t <sub>HCKL</sub>	Input High to Low (pad to S-module input)		3.0		3.4		3.9		4.5		5.5	ns
t <sub>HPWH</sub>	Minimum Pulse Width High	1.9		2.4		3.3		3.8		4.8		ns
t <sub>HPWL</sub>	Minimum Pulse Width Low	1.9		2.4		3.3		3.8		4.8		ns
t <sub>HCKSW</sub>	Delta High to Low, Low Slew		0.3		0.3		0.3		0.3		0.3	ns
t <sub>HP</sub>	Minimum Period	4.0		5.0		6.8		8.0		10.0		ns
f <sub>HMAX</sub>	Maximum Frequency		250		200		150		125		100	MHz
<b>Routed Array Clock Networks</b>												
t <sub>RCKH</sub>	Input Low to High (FO = 64)		3.7		4.1		4.7		5.5		9.0	ns
t <sub>RCKL</sub>	Input High to Low (FO = 64)		4.0		4.5		5.1		6.0		9.0	ns
t <sub>RPWH</sub>	Min. Pulse Width High (FO = 64)	3.3		3.8		4.2		4.9		6.5		ns
t <sub>RPWL</sub>	Min. Pulse Width Low (FO = 64)	3.3		3.8		4.2		4.9		6.5		ns
t <sub>RCKSW</sub>	Maximum Skew (FO = 128)		0.7		0.8		0.9		1.0		1.0	ns
t <sub>RP</sub>	Minimum Period (FO = 64)	6.8		8.0		8.7		10.0		13.4		ns
f <sub>RMAX</sub>	Maximum Frequency (FO = 64)		150		125		115		100		75	MHz
<b>Clock-to-Clock Skews</b>												
t <sub>IOHCKSW</sub>	I/O Clock to H-Clock Skew	0.0	1.7	0.0	1.8	0.0	2.0	0.0	2.2	0.0	3.0	ns
t <sub>IORCKSW</sub>	I/O Clock to R-Clock Skew (FO = 64) (FO = 144)	0.0	1.0	0.0	1.0	0.0	1.0	0.0	1.0	0.0	3.0	ns
		0.0	3.0	0.0	3.0	0.0	3.0	0.0	3.0	0.0	3.0	
t <sub>HRCKSW</sub>	H-Clock to R-Clock Skew (FO = 64) (FO = 144)	0.0	1.0	0.0	1.0	0.0	1.0	0.0	1.0	0.0	1.0	ns
		0.0	3.0	0.0	3.0	0.0	3.0	0.0	3.0	0.0	3.0	

**Notes:**

1. The –2 and –3 speed grades have been discontinued. Refer to PDN 0104, PDN 0203, PDN 0604, and PDN 1004 at <http://www.microsemi.com/soc/support/notifications/default.aspx#pdn>.
2. Delays based on 35 pF loading.



## A14100A, A14V100A Timing Characteristics

**Table 2-34 • A14100A, A14V100A Worst-Case Commercial Conditions, VCC = 4.75 V, T<sub>J</sub> = 70°C<sup>1</sup>**

Logic Module Propagation Delays <sup>2</sup>		–3 Speed <sup>3</sup>		–2 Speed <sup>3</sup>		–1 Speed		Std. Speed		3.3 V Speed <sup>1</sup>		Units
Parameter/Description		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t <sub>PD</sub>	Internal Array Module		2.0		2.3		2.6		3.0		3.9	ns
t <sub>CO</sub>	Sequential Clock to Q		2.0		2.3		2.6		3.0		3.9	ns
t <sub>CLR</sub>	Asynchronous Clear to Q		2.0		2.3		2.6		3.0		3.9	ns
<b>Predicted Routing Delays<sup>4</sup></b>												
t <sub>RD1</sub>	FO = 1 Routing Delay		0.9		1.0		1.1		1.3		1.7	ns
t <sub>RD2</sub>	FO = 2 Routing Delay		1.2		1.4		1.6		1.8		2.4	ns
t <sub>RD3</sub>	FO = 3 Routing Delay		1.4		1.6		1.8		2.1		2.8	ns
t <sub>RD4</sub>	FO = 4 Routing Delay		1.7		1.9		2.2		2.5		3.3	ns
t <sub>RD8</sub>	FO = 8 Routing Delay		2.8		3.2		3.6		4.2		5.5	ns
<b>Logic Module Sequential Timing</b>												
t <sub>SUD</sub>	Flip-Flop Data Input Setup	0.5		0.6		0.8		0.8		0.8		ns
t <sub>HD</sub>	Flip-Flop Data Input Hold	0.0		0.0		0.5		0.5		0.5		ns
t <sub>SUD</sub>	Latch Data Input Setup	0.5		0.6		0.8		0.8		0.8		ns
t <sub>HD</sub>	Latch Data Input Hold	0.0		0.0		0.5		0.5		0.5		ns
t <sub>WASYN</sub>	Asynchronous Pulse Width	2.4		3.2		3.8		4.8		6.5		ns
t <sub>WCLKA</sub>	Flip-Flop Clock Pulse Width	2.4		3.2		3.8		4.8		6.5		ns
t <sub>A</sub>	Flip-Flop Clock Input Period	5.0		6.8		8.0		10.0		13.4		ns
f <sub>MAX</sub>	Flip-Flop Clock Frequency		200		150		125		100		75	MHz

**Notes:**

1. VCC = 3.0 V for 3.3 V specifications.
2. For dual-module macros, use t<sub>PD</sub> + t<sub>RD1</sub> + t<sub>PDn</sub> + t<sub>CO</sub> + t<sub>RD1</sub> + t<sub>PDn</sub> or t<sub>PD1</sub> + t<sub>RD1</sub> + t<sub>SUD</sub>, whichever is appropriate.
3. The –2 and –3 speed grades have been discontinued. Refer to PDN 0104, PDN 0203, PDN 0604, and PDN 1004 at <http://www.microsemi.com/soc/support/notifications/default.aspx#pdn>.
4. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.

## A14100A, A14V100A Timing Characteristics (continued)

**Table 2-37 • A14100A, A14V100A Worst-Case Commercial Conditions, VCC = 4.75 V, T<sub>J</sub> = 70°C**

Dedicated (hardwired) I/O Clock Network		–3 Speed <sup>1</sup>		–2 Speed <sup>1</sup>		–1 Speed		Std. Speed		3.3 V Speed <sup>1</sup>		Units
Parameter/Description		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t <sub>IOCKH</sub>	Input Low to High (pad to I/O module input)		2.3		2.6		3.0		3.5		4.5	ns
t <sub>IOPWH</sub>	Minimum Pulse Width High	2.4		3.3		3.8		4.8		6.5		ns
t <sub>IPOWL</sub>	Minimum Pulse Width Low	2.4		3.3		3.8		4.8		6.5		ns
t <sub>IOSAPW</sub>	Minimum Asynchronous Pulse Width	2.4		3.3		3.8		4.8		6.5		ns
t <sub>IOCKSW</sub>	Maximum Skew		0.6		0.6		0.7		0.8		0.6	ns
t <sub>IOP</sub>	Minimum Period	5.0		6.8		8.0		10.0		13.4		ns
f <sub>IOMAX</sub>	Maximum Frequency		200		150		125		100		75	MHz
<b>Dedicated (hardwired) Array Clock</b>												
t <sub>HCKH</sub>	Input Low to High (pad to S-module input)		3.7		4.1		4.7		5.5		7.0	ns
t <sub>HCKL</sub>	Input High to Low (pad to S-module input)		3.7		4.1		4.7		5.5		7.0	ns
t <sub>HPWH</sub>	Minimum Pulse Width High	2.4		3.3		3.8		4.8		6.5		ns
t <sub>HPWL</sub>	Minimum Pulse Width Low	2.4		3.3		3.8		4.8		6.5		ns
t <sub>HCKSW</sub>	Delta High to Low, Low Slew		0.6		0.6		0.7		0.8		0.6	ns
t <sub>HP</sub>	Minimum Period	5.0		6.8		8.0		10.0		13.4		ns
f <sub>HMAX</sub>	Maximum Frequency		200		150		125		100		75	MHz
<b>Routed Array Clock Networks</b>												
t <sub>RCKH</sub>	Input Low to High (FO = 64)		6.0		6.8		7.7		9.0		11.8	ns
t <sub>RCKL</sub>	Input High to Low (FO = 64)		6.0		6.8		7.7		9.0		11.8	ns
t <sub>RPWH</sub>	Min. Pulse Width High (FO = 64)	4.1		4.5		5.4		6.1		8.2		ns
t <sub>RPWL</sub>	Min. Pulse Width Low (FO = 64)	4.1		4.5		5.4		6.1		8.2		ns
t <sub>RCKSW</sub>	Maximum Skew (FO = 128)		1.2		1.4		1.6		1.8		1.8	ns
t <sub>RP</sub>	Minimum Period (FO = 64)	8.3		9.3		11.1		12.5		16.7		ns
f <sub>RMAX</sub>	Maximum Frequency (FO = 64)		120		105		90		80		60	MHz
<b>Clock-to-Clock Skews</b>												
t <sub>IOHCKSW</sub>	I/O Clock to H-Clock Skew	0.0	2.6	0.0	2.7	0.0	2.9	0.0	3.0	0.0	3.0	ns
t <sub>IORCKSW</sub>	I/O Clock to R-Clock Skew (FO = 64) (FO = 350)	0.0	1.7	0.0	1.7	0.0	1.7	0.0	1.7	0.0	5.0	ns
		0.0	5.0	0.0	5.0	0.0	5.0	0.0	5.0	0.0	5.0	
t <sub>HRCKSW</sub>	H-Clock to R-Clock Skew (FO = 64) (FO = 350)	0.0	1.3	0.0	1.0	0.0	1.0	0.0	1.0	0.0	1.0	ns
		0.0	3.0	0.0	3.0	0.0	3.0	0.0	3.0	0.0	3.0	

Notes: \*

1. The –2 and –3 speed grades have been discontinued. Refer to PDN 0104, PDN 0203, PDN 0604, and PDN 1004 at <http://www.microsemi.com/soc/support/notifications/default.aspx#pdn>.
2. Delays based on 35 pF loading.

## Pin Descriptions

### **CLKA**                      **Clock A (Input)**

Clock input for clock distribution networks. The Clock input is buffered prior to clocking the logic modules. This pin can also be used as an I/O.

### **CLKB**                      **Clock B (Input)**

Clock input for clock distribution networks. The Clock input is buffered prior to clocking the logic modules. This pin can also be used as an I/O.

### **GND**                      **Ground**

LOW supply voltage.

### **HCLK**                      **Dedicated (Hard-wired) Array Clock (Input)**

Clock input for sequential modules. This input is directly wired to each S-Module and offers clock speeds independent of the number of S-Modules being driven. This pin can also be used as an I/O.

### **I/O**                      **Input/Output (Input, Output)**

The I/O pin functions as an input, output, three-state, or bidirectional buffer. Input and output levels are compatible with standard TTL and CMOS specifications. Unused I/O pins are tristated by the Designer Series software.

### **IOCLK**                      **Dedicated (Hard-wired) I/O Clock (Input)**

Clock input for I/O modules. This input is directly wired to each I/O module and offers clock speeds independent of the number of I/O modules being driven. This pin can also be used as an I/O.

### **IOPCL**                      **Dedicated (Hard-wired) I/O Preset/Clear (Input)**

Input for I/O preset or clear. This global input is directly wired to the preset and clear inputs of all I/O registers. This pin functions as an I/O when no I/O preset or clear macros are used.

### **MODE**                      **Mode (Input)**

The MODE pin controls the use of diagnostic pins (DCLK, PRA, PRB, SDI). When the MODE pin is HIGH, the special functions are active. When the MODE pin is LOW, the pins function as I/Os. To provide Actionprobe capability, the MODE pin should be terminated to GND through a 10K resistor so that the MODE pin can be pulled high when required.

### **NC**                      **No Connection**

This pin is not connected to circuitry within the device.

### **PRA**                      **Probe A (Output)**

The Probe A pin is used to output data from any user-defined design node within the device. This independent diagnostic pin can be used in conjunction with the Probe B pin to allow real-time diagnostic output of any signal path within the device. The Probe A pin can be used as a user-defined I/O when debugging has been completed. The pin's probe capabilities can be permanently disabled to protect programmed design confidentiality. PRA is accessible when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

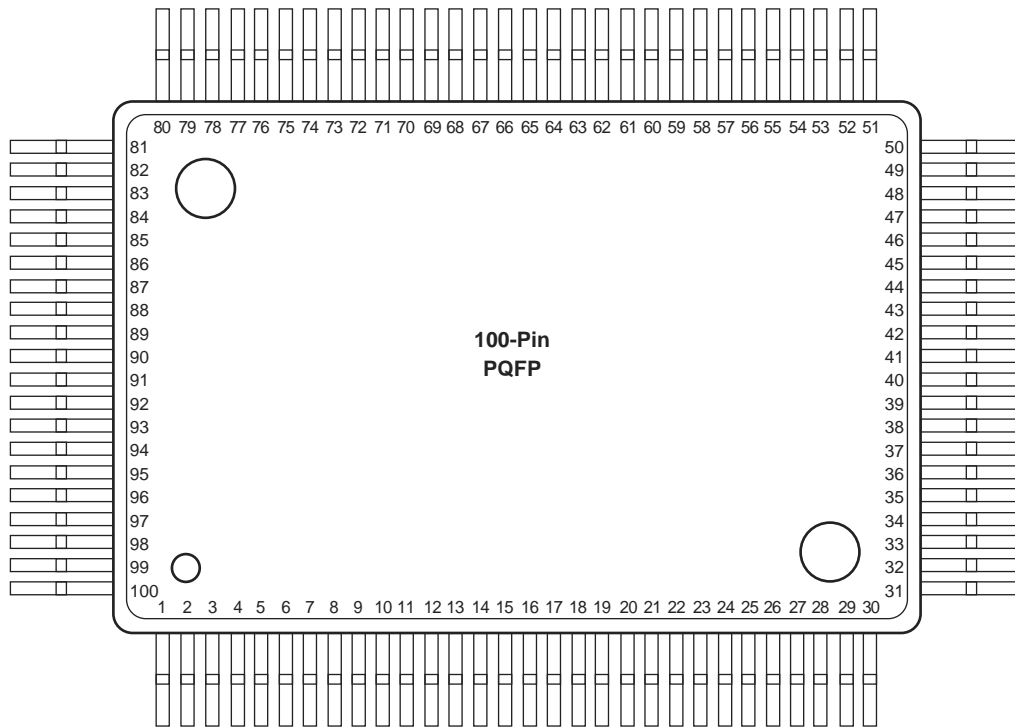
### **PRB**                      **Probe B (Output)**

The Probe B pin is used to output data from any user-defined design node within the device. This independent diagnostic pin can be used in conjunction with the Probe A pin to allow real-time diagnostic output of any signal path within the device. The Probe B pin can be used as a user-defined I/O when debugging has been completed. The pin's probe capabilities can be permanently disabled to protect programmed design confidentiality. PRB is accessible when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

### **SDI**                      **Serial Data Input (Input)**

Serial data input for diagnostic probe and device programming. SDI is active when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

## PQ100



*Note:* This is the top view of the package.

### Note

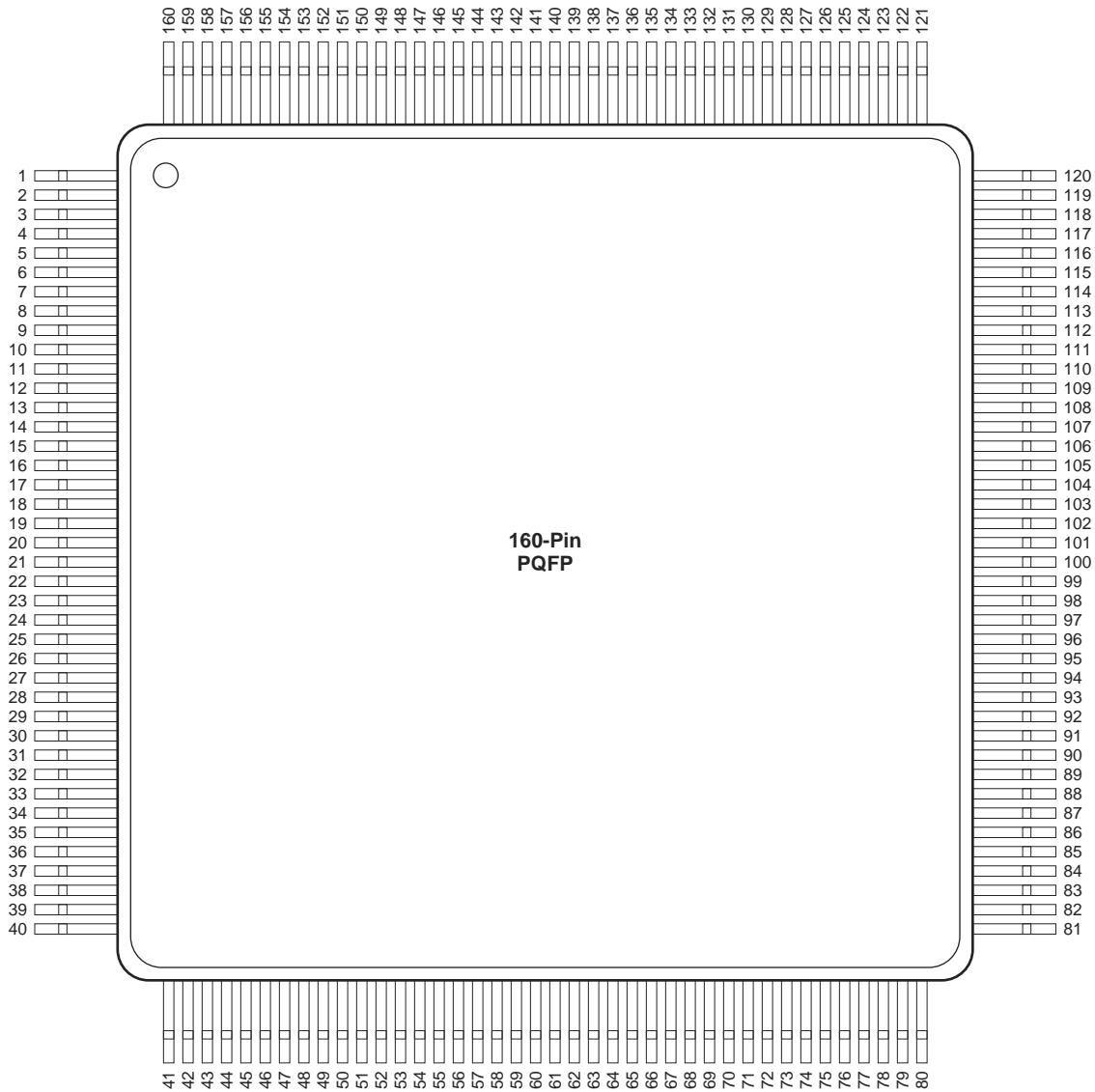
For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>

PQ100		
Pin Number	A1415 Function	A1425 Function
2	IOCLK, I/O	IOCLK, I/O
14	CLKA, I/O	CLKA, I/O
15	CLKB, I/O	CLKB, I/O
16	VCC	VCC
17	GND	GND
18	VCC	VCC
19	GND	GND
20	PRA, I/O	PRA, I/O
27	DCLK, I/O	DCLK, I/O
28	GND	GND
29	SDI, I/O	SDI, I/O
34	MODE	MODE
35	VCC	VCC
36	GND	GND
47	GND	GND
48	VCC	VCC
61	PRB, I/O	PRB, I/O
62	GND	GND
63	VCC	VCC
64	GND	GND
65	VCC	VCC
67	HCLK, I/O	HCLK, I/O
77	SDO	SDO
78	IOPCL, I/O	IOPCL, I/O
79	GND	GND
85	VCC	VCC
86	VCC	VCC
87	GND	GND
96	VCC	VCC
97	GND	GND

**Notes:**

1. All unlisted pin numbers are user I/Os.
2. NC denotes no connection.
3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

## PQ160

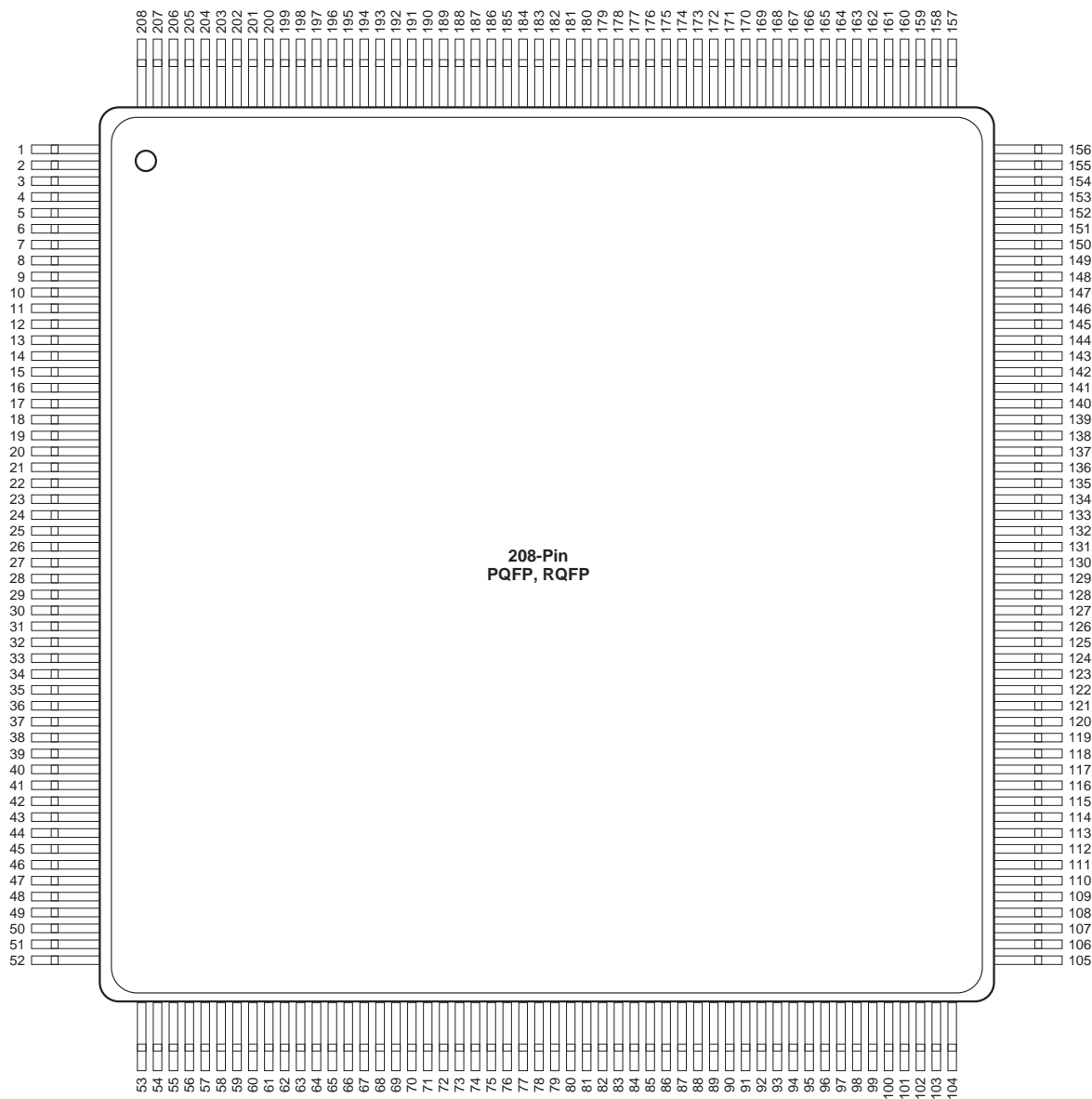


*Note:* This is the top view of the package

### Note

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>

## PQ208, RQ208



*Note:* This is the top view of the package

### Note

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>

CQ132		CQ132	
Pin Number	A1425 Function	Pin Number	A1425 Function
1	NC	67	NC
2	GND	74	GND
3	SDI, I/O	75	VCC
9	MODE	78	VCC
10	GND	89	VCC
11	VCC	90	GND
22	VCC	91	VCC
26	GND	92	GND
27	VCC	98	IOCLK, I/O
34	NC	99	NC
36	GND	100	NC
42	GND	101	GND
43	VCC	106	GND
48	PRB, I/O	107	VCC
50	HCLK, I/O	116	CLKA, I/O
58	GND	117	CLKB, I/O
59	VCC	118	PRA, I/O
63	SDO	122	GND
64	IOPCL, I/O	123	VCC
65	GND	131	DCLK, I/O
66	NC	132	NC

*Notes:*

1. All unlisted pin numbers are user I/Os.
2. NC denotes no connection.
3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

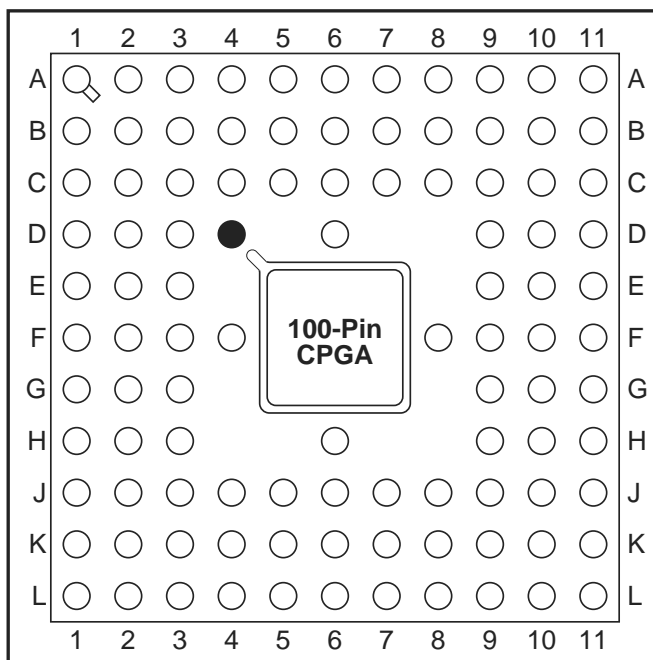


BG313	
A14100, A14V100 Function	Location
CLKA or I/O	J13
CLKB or I/O	G13
DCLK or I/O	B2
GND	A1, A25, AD2, AE25, J21, L13, M12, M14, N11, N13, N15, P12, P14, R13
HCLK or I/O	T14
IOCLK or I/O	B24
IOPCL or I/O	AD24
MODE	G3
NC	A3, A13, A23, AA5, AA9, AA23, AB2, AB4, AB20, AC13, AC25, AD22, AE1, AE21, B14, C5, C25, D4, D24, E3, E21, F6, F10, F16, G1, G25, H18, H24, J1, J7, J25, K12, L15, L17, M6, N1, N5, N7, N21, N23, P20, R11, T6, T8, U9, U13, U21, V16, W7, Y20, Y24
PRA or I/O	H12
PRB or I/O	AD12
SDI or I/O	C1
SDO	AE23
VCC	AB18, AD6, AE13, C13, C19, E13, G9, H22, K8, K20, M16, N3, N9, N25, U5, W13, V2, V22, V24

*Notes:*

1. All unlisted pin numbers are user I/Os.
2. NC denotes no connection.
3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

## PG100



● Orientation Pin

*Note:* This is the top view.

### **Note**

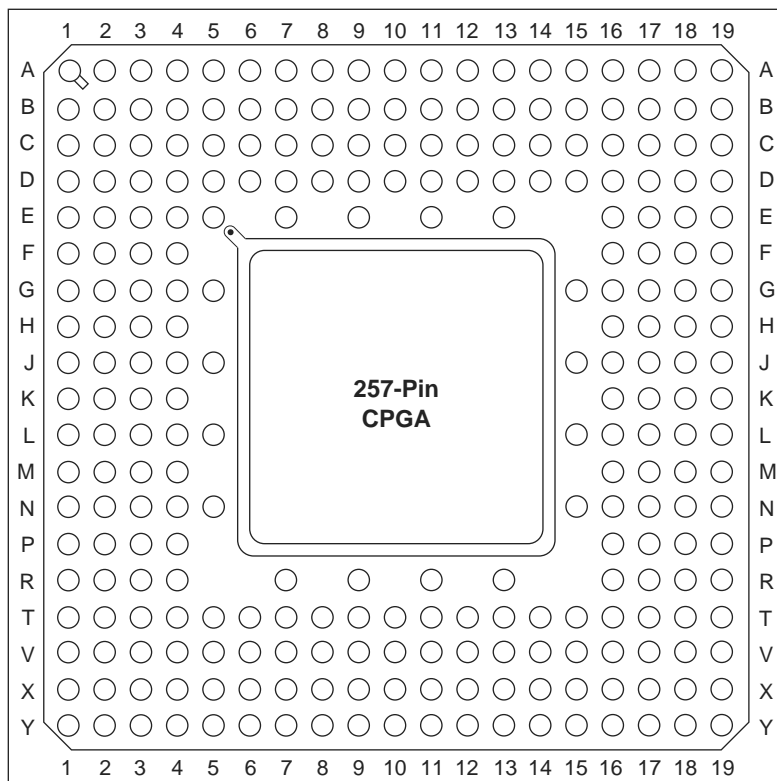
For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>

PG175	
A1440 Function	Location
CLKA or I/O	C9
CLKB or I/O	A9
DCLK or I/O	D5
GND	D4, D8, D11, D12, E4, E14, H4, H12, L4, L12, M4, M8, M12
HCLK or I/O	R8
IOCLK or I/O	E12
IOPCL or I/O	P13
MODE	F3
NC	A1, A2, A15, B2, B3, P2, P14, R1, R2, R14, R15
PRA or I/O	B8
PRB or I/O	R7
SDI or I/O	D3
SDO	N12
VCC	C3, C8, C13, E15, H3, H13, L1, L14, N3, N8, N13

**Notes:**

1. All unlisted pin numbers are user I/Os.
2. NC denotes no connection.
3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.
4. The PG175 package has been discontinued.

## PG257



*Note: This is the top view.*

### **Note**

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>

Revision	Changes	Page
Revision 2 (continued)	In the "Package Pin Assignments" section, notes were added to the pin tables for the following packages, stating that they are discontinued: "BG225" "PG100" "PG133" "PG175"	3-20 3-24 3-26 3-28
Revision 1 (June 2006)	RoHS compliant information was added to the "Ordering Information" section.	II